

Low-Power, Rail-to-Rail Output, 12-Bit Serial InputDIGITAL-TO-ANALOG CONVERTER

The HT7312A is a low-power, single, 12-bit buffered voltage output Digital-to-Analog Converter (DAC). Its on-chip preci-sion output amplifier allows rail-to-rail output swing to be achieved. The HT7312A uses a versatile three-wire serial interface that operates at clock rates up to 30MHz and is compatible with standard SPI™, QSPI™, Microwire™, and DSP interfaces.

The reference for the HT7312A is derived from the power supply, resulting in the widest dynamic output range possible. The HT7312A incorporates a power-on reset circuit that ensures that the DAC output powers up at 0V and remains there until a valid write takes place in the device. The HT7312A contains a power-down feature, accessed over the serial interface, that can reduce the current consumption of the device to 50nA at 5V.

The low power consumption of this part in normal operation makes it ideally suited to portable battery-operated equip-ment. The power consumption is 0.7mW at 5V reducing to 1µW in power-down mode.

FEATURES

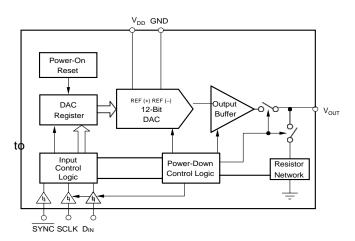
- micro POWER OPERATION: 135µAat 5V
- POWER -DOWN: 200nA at 5V, 50nA at 3V
- POWER SUPPLY: +2.7V to +5.5V
- TESTED MONOTONIC BY DESIGN
- POWER -ON RESET TO
- THREE POWER -DOWNFUNCTIONS
- LOW POWER SERIAL INTERFACE WITH SCHMITT -TRIGGERED INPUTS
- ON-CHIPOUTPUTBUFFERAMPLIFIER, **RAIL -TO -RAIL OPERATION**
- SYNCINTERRUPT FACILITY

APPLICATIONS

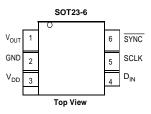
- PORTABLE BATTERY-POWERED INSTRUMENTS
- DIGITAL GAIN AND OFFSET ADJUSTMENT
- PROGRAMMABLE VOLTAGE
- AND CURRENT SOURCES

ORDERING INFORMATION HT7312ARTZ T_A=-40° to 125°C for all packages.

Typical Application Circuit



PIN CONFIGURATIONS





ABSOLUTE MAXIMUM RATINGS(1)

V _{DD} to GND	
Digital Input Voltage to GND	-0.3V to +Vpp + 0.3V
1	
Vout to GND	0.3V to +V _{DD} + 0.3V
Operating Temperature Range	40°C to +105°C
Storage Temperature Range	65°C to +150°C
Junction Temperature Range (T _J max)	+150°C
SOT23 Package:	
Power Dissipation	(T _J max — ^{T_A)/ _{JA}}
JA Thermal Impedance	
Lead Temperature, Soldering:	
	.04500
Vapor Phase(60s)	
Infrared (15s)	+220°C
MSOP Package:	.,
Power Dissipation	(T _. max — T ^{A)/JA}
JA Thermal Impedance	206°C/W
JC Thermal Impedance	
Lead Temperature, Soldering:	
Vapor Phase(60s)	+215°C
Infrared (15s)	+220°C

NOTE: (1) Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.

PIN DESCRIPTION (SOT23-6)

		· · · · · · · · · · · · · · · · · · ·
PIN	NAME	DESCRIPTION
1	V _{OUT}	Analog output voltage from DAC. The output amplifier has rail-to-rail operation.
2	GND	Ground reference pointforallcircuitry on the part.
3	V_{DD}	Power Supply Input, +2.7V to 5.5V.
4	D _{IN}	Serial Data Input. Data is clocked into the 16-bit input shift register on the falling edge of the serial clock input.
5	SCLK	Serial Clock Input. Data can be transferred at rates up to 30MHz.
6	SYNC	Level triggered control input (active LOW). This is the frame sychronization signal for the input data. When SYNG-goes LOW, it enables the input shift register and data is transferred in on the falling edgesofthefollowingclocks. The DAC is updated following the 16th clock cycle unless SYNC is taken HIGH before this edge, in which case the rising edge of SYNC acts as an interrupt and the write sequence is ignored by the HT7312A.



			HT7312A			
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
STATIC PERFORMANCE (1) Resolution Relative Accuracy Differential Nonlinearity Zero Code Error Full-Scale Error Gain Error Zero Code Error Drift Gain Temperature Coefficient	Tested Monotonic by Design All Zeroes Loaded to DAC Register All Ones Loaded to DAC Register	12	+5 -0.15 -20 -5	±8 ±1 +20 -1.25 ±1.25	Bits LSB LSB mV % of FSR % of FSR µV/°C ppmofFSR/°C	
OUTPUT CHARACTERISTICS (2) Output Voltage Range Output Voltage Settling Time	1/4 Scale to 3/4 Scale Change (400 _H to C00 _H) R _L =2kΩ; 0pF < C _L < 200pF R _L =2kΩ; C _L =500pF	0	8	V _{DD}	V µs µs	
Slew Rate	Ν[=2κ2, Θ[=300βF	1	12		V/µs	
Capacitive Load Stability Code Change Glitch Impulse Digital Feedthrough DC Output Impedance Short-Circuit Current	$R_L = x$ $R_L = 2k\Omega$ 1LSB Change Around Major Carry $V_{DD} = +5V$ $V_{DD} = +3V$ Coming Out of Power-Down Mode		470 1000 20 0.5 1 50 20		pF pF nV-s nV-s Ω mA mA	
Power-Up Time	Coming Out of Power-Down Mode $V_{DD} = +5V$ Coming Out of Power-Down Mode $V_{DD} = +3V$		2.5 5		μs μs	
LOGIC INPUTS (2) Input Current V _{IN} L, Input Low Voltage V _{IN} L, Input Low Voltage V _{IN} H, Input High Voltage V _{IN} H, Input High Voltage Pin Capacitance	V _{DD} =+5V V _{DD} =+3V V _{DD} =+5V V _{DD} =+3V	2.4 2.1		±1 0.8 0.6	μΑ V V V V pF	
POWER REQUIREMENTS V_{DD} $I_{DD} (normal mode)$ $V_{DD} = +3.6V \text{ to } +5.5V$ $V_{DD} = +2.7V \text{ to } +3.6V$ $I_{DD} (all power-down modes)$ $V_{DD} = +3.6V \text{ to } +5.5V$ $V_{DD} = +2.7V \text{ to } +3.6V$	$\begin{aligned} \text{DACActive} & \text{andExcludingLoadCurrent} \\ & V_{\text{IH}} \! = \! V_{\text{DD}} \text{andV}_{\text{IL}} \! = \! \text{GND} \\ & V_{\text{IH}} \! = \! V_{\text{DD}} \text{andV}_{\text{IL}} \! = \! \text{GND} \\ & V_{\text{IH}} \! = \! V_{\text{DD}} \text{andV}_{\text{IL}} \! = \! \text{GND} \\ & V_{\text{IH}} \! = \! V_{\text{DD}} \text{andV}_{\text{IL}} \! = \! \text{GND} \\ & V_{\text{IH}} \! = \! V_{\text{DD}} \text{andV}_{\text{IL}} \! = \! \text{GND} \end{aligned}$	2.7	135 115 0.2 0.05	5.5 200 160 1	ν μΑ μΑ μΑ μΑ	
POWER EFFICIENCY I _{OUT} /I _{DD}	I _{LOAD} = 2mA. V _{DD} = +5V		93		%	
TEMPERATURE RANGE Specified Performance		-40		+105	°C	

NOTES: (1) Linearity calculated using a reduced code range of 48 to 4047; output unloaded. (2) Guaranteed by design and characterization, not production tested.



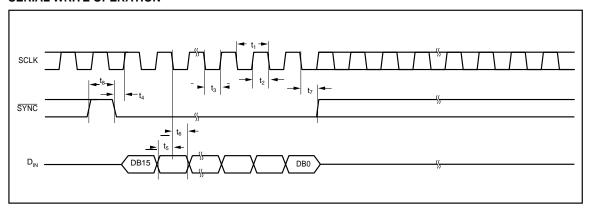
TIMING CHARACTERISTICS(1, 2)

 V_{DD} = +2.7V to +5.5V; all specifications -40°C to +105°C, unless otherwise noted.

		HT7312A							
PARAMETER	DESCRIPTION	CONDITIONS	MIN	ТҮР					
MAX	UNITS t (3)	SCLK Cycle Time							
		$V_{DD} = 2.7V \text{ to } 3.6V$	50		ns				
		$V_{DD} = 3.6V \text{ to } 5.5V$	33		ns				
t ₂	SCLK HIGH Time								
		$V_{DD} = 2.7V \text{ to } 3.6V$	13		ns				
		$V_{DD} = 3.6V \text{ to } 5.5V$	13		ns				
t ₃	SCLK LOW Time								
		$V_{DD} = 2.7V \text{ to } 3.6V$	22.5		ns				
	<u> </u>	V _{DD} = 3.6V to 5.5V	13		ns				
t ₄	SYNC to SCLK Rising Edge Setup Time								
		V _{DD} = 2.7V to 3.6V	0		ns				
		V _{DD} = 3.6V to 5.5V	0		ns				
t ₅	Data Setup Time	100 0.01 10 0.01							
Ü		$V_{DD} = 2.7V \text{ to } 3.6V$	5		ns				
		V _{DD} = 3.6V to 5.5V	5		ns				
t ₆	Data Hold Time								
		$V_{DD} = 2.7V \text{ to } 3.6V$	4.5		ns				
		V _{DD} = 3.6V to 5.5V	4.5		ns				
t ₇	SCLK Falling Edge to								
	SYNC Rising Edge								
		V _{DD} = 2.7V to 3.6V	0		ns				
t ₈	Minimum SYNC HIGH Time	V _{DD} = 3.6V to 5.5V	0		ns				
		V _{DD} = 2.7V to 3.6V	50		ns				
		V _{DD} = 3.6V to 5.5V	33		ns				

NOTES: (1) All input signals are specified with $t_R = t_F = 5$ ns (10% to 90% of V_{DD}) and timed from a voltage level of $(V_{IL} + V_{IH})/2$. (2) See Serial Write Operation timing diagram, below. (3) Maximum SCLK frequency is 30MHz at $V_{DD} = +3.6$ V to +5.5V and 20MHz at $V_{DD} = +2.7$ V to +3.6V.

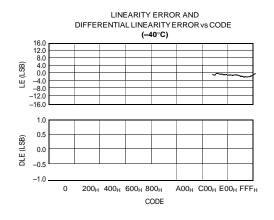
SERIAL WRITE OPERATION

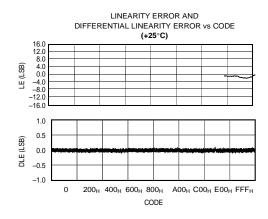


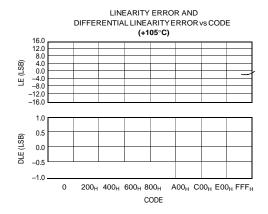


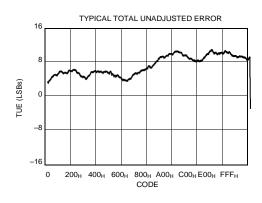
TYPICAL CHARACTERISTICS: V_{DD} = +5V

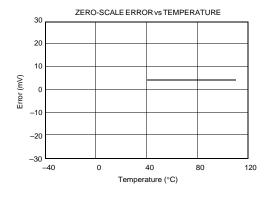
At $T_A = +25$ °C, $+V_{DD} = +5V$, unless otherwise noted.

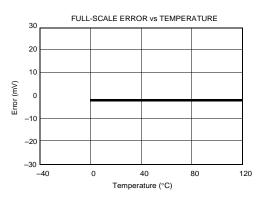








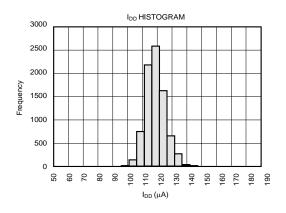


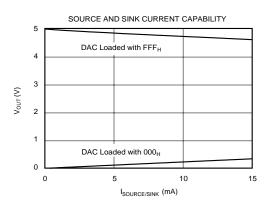


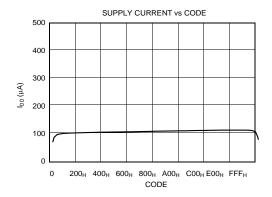


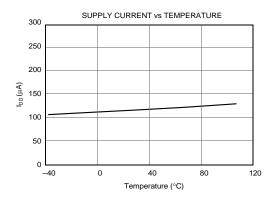
TYPICAL CHARACTERISTICS: V_{DD} = +5V (Cont.)

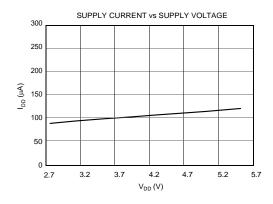
At $T_A = +25$ °C, $+V_{DD} = +5V$, unless otherwise noted.

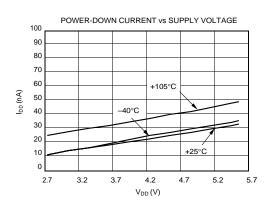








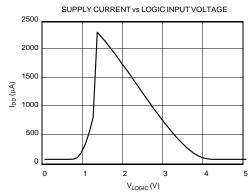




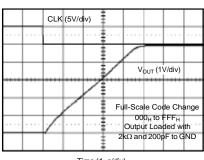


TYPICAL CHARACTERISTICS: V_{DD} = +5V (Cont.)

At $T_A = +25$ °C, $+V_{DD} = +5V$, unless otherwise noted.

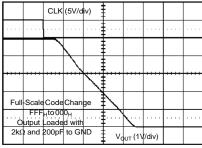


FULL-SCALE SETTLINGTIME



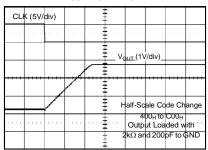
Time (1µs/div)

FULL-SCALE SETTLINGTIME



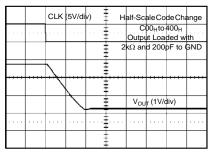
Time (1µs/div)

HALF-SCALE SETTLING TIME



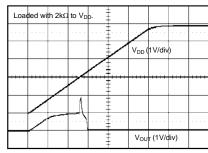
Time (1µs/div)

HALF-SCALESETTLINGTIME



Time (1µs/div)

POWER-ON RESET TO 0V

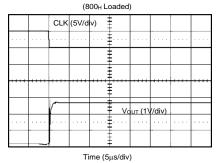


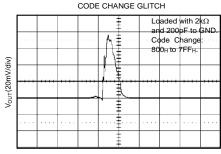
Time (20µs/div)



TYPICAL CHARACTERISTICS: V_{DD} = +5V (Cont.)

At T_A = +25°C, +V_{DD} = +5V, unless otherwise noted. EXITING POWER-DOWN

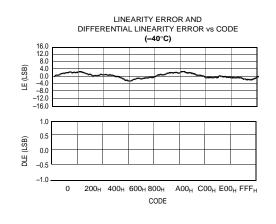


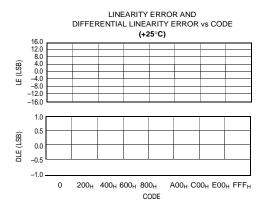


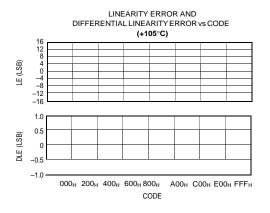
Time (0.5µs/div)

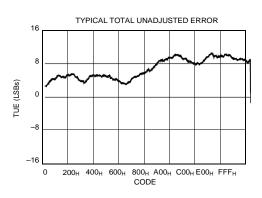
TYPICAL CHARACTERISTICS: V_{DD} = +2.7V

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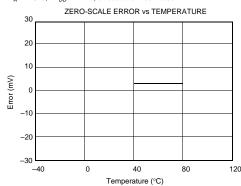


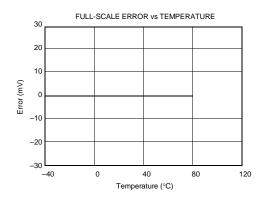


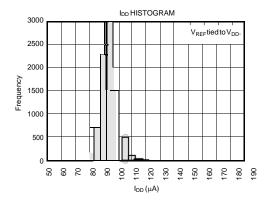


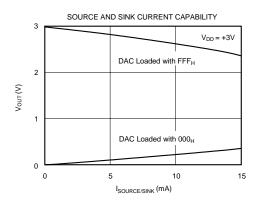
TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

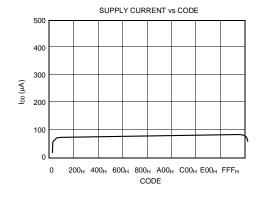
At $T_A = +25$ °C, $+V_{DD} = +2.7$ V, unless otherwise noted.

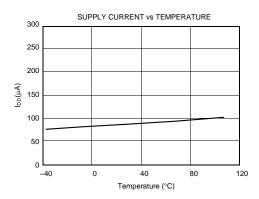








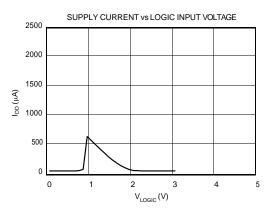


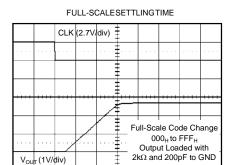




TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

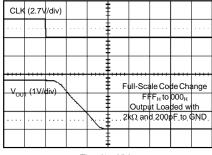
At $T_A = +25$ °C, $+V_{DD} = +2.7$ V, unless otherwise noted.





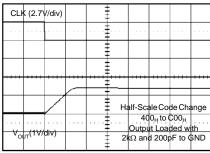
Time (1µs/div)





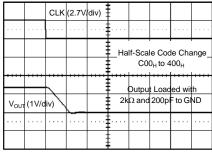
Time (1µs/div)

HALF-SCALE SETTLING TIME



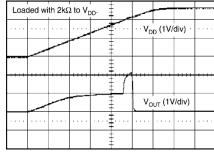
Time (1µs/div)

HALF-SCALESETTLINGTIME



Time (1µs/div)

POWER-ON RESET to 0V



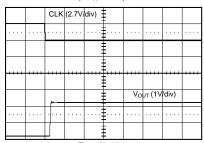
Time (20µs/div)



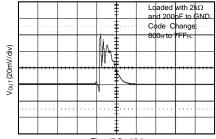
TYPICAL CHARACTERISTICS: V_{DD} = +2.7V (Cont.)

At T_A = +25°C, +V_{DD} = +2.7V, unless otherwise noted.

EXITING POWER-DOWN (800_H Loaded)



Time (5µs/div)



CODE CHANGE GLITCH

Time (0.5µs/div)

THEORY OF OPERATION

DAC SECTION

The HT7312A is fabricated using a CMOS process. The architecture consists of a string DAC followed by an output buffer amplifier. Since there is no reference input pin, the power supply (V_{DD}) acts as the reference. Figure 1 shows a block diagram of the DAC architecture.

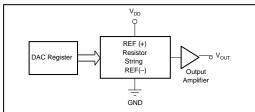


FIGURE 1. HT7312A Architecture.

The input coding to the HT7312A is straight binary, so the ideal output voltage is given by:

$$V_{OUT} = V_{DD} \underbrace{\frac{D}{4096}}$$

where D = decimal equivalent of the binary code that is loaded to the DAC register; it can range from 0 to 4095.

RESISTOR STRING

The resistor string section is shown in Figure 2. It is simply a string of resistors, each of value R. The code loaded into the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier by closing one of the switches connecting the string to the amplifier. It is tested monotonic because it is a string of resistors.

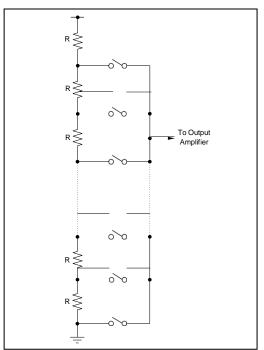


FIGURE 2. Resistor String.

OUTPUT AMPLIFIER

The output buffer amplifier is capable of generating rail-to-rail voltages on its output which gives an output range of 0V to V_DD. It is capable of driving a load of $2\kappa\Omega$ in parallel with 1000pF to GND. The source and sink capabilities of the output amplifier can be seen in the typical characteristics. The slew rate is $1V/\mu s$ with a half-scale settling time of $8\mu s$ with the output unloaded.



SERIAL INTERFACE

The HT7312A has a three-wire serial interface (SYNC, SCLK, and D_{IN}), which is compatible with SPI, QSPI, and Microwire interface standards as well as most Digital Signal Processors (DSPs). See the Serial Write Operation timing diagram for an example of a typical write sequence.

The write sequence begins by bringing the SYNC line LOW. Data from the $D_{\rm IN}$ line is clocked into the 16-bit shift register on the falling edge of SCLK. The serial clock frequency can be as high as 30MHz, making the HT7312A compatible with high-speed DSPs. On the 16th falling edge of the serial clock, the last data bit is clocked in and the programmed function is executed (i.e., a change in DAC register contents and/or a change in the mode of operation).

At this point, the SYNC line may be kept LOW or brought HIGH. In either case, it must be brought HIGH for a minimum of 33ns before the next write sequence so that a falling edge of \$\overline{SYNC}\$ can initiate the next write sequence. Since the \$\overline{SYNC}\$ buffer draws more current when the \$\overline{SYNC}\$ signal is HIGH than it does when it is LOW, \$\overline{SYNC}\$ should be idled LOW between write sequences for lowest power operation of the part. As mentioned above, however, it must be brought HIGH again just before the nextwrite sequence.

INPUT SHIFT REGISTER

The input shift register is 16 bits wide, as shown in Figure 3. The first two bits are "don't cares". The next two bits (PD1 and PD0) are control bits that control which mode of operation the part is in (normal mode or one of three power-down modes). There is a more complete description of the various modes in the Power-Down Modes section. The next 12 bits are the data bits. These are transferred to the DAC register on the 16th falling edge of SCLK.

SYNC INTERRUPT

In a normal write sequence, the $\overline{\text{SYNC}}$ line is kept LOW for at least 16 falling edges of SCLK and the DAC is updated on the 16th falling edge. However, if $\overline{\text{SYNC}}$ is brought HIGH before the 16th falling edge, this acts as an interrupt to the

write sequence. The shift register is reset and the write sequence is seen as invalid. Neither an update of the DAC register contents or a change in the operating mode occurs, as shown in Figure 4.

POWER-ON RESET

The HT7312A contains a power-on reset circuit that controls the output voltage during power-up. On power-up, the DAC register is filled with zeros and the output voltage is 0V; it remains there until a valid write sequence is made to the DAC. This is useful in applications where it is important to know the state of the output of the DAC while it is in the process of powering up.

POWER-DOWN MODES

The HT7312A contains four separate modes of operation. These modes are programmable by setting two bits (PD1 and PD0) in the control register. Table I shows how the state of the bits corresponds to the mode of operation of the device.

DB13	DB12	OPERATING MODE
0	0	Normal Operation
		Power-Down Modes:
0	1	Output 1kΩ to GND
1	0	Output 100kΩ to GND
1	1	High-Z

TABLE I. Modes of Operation for the HT7312A.

When both bits are set to 0, the part works normally with its normal power consumption of 135µA at 5V. However, for the three power-down modes, the supply current falls to 200nA at 5V (50nA at 3V). Not only does the supply current fall, but the output stage is also internally switched from the output of the amplifier to a resistor network of known values. This has the advantage that the output impedance of the part is known while the part is in power-down mode. There are three different options. The output is connected internally to GND through a $1 k\Omega$ resistor, a $100 k\Omega$ resistor, or it is left opencircuited (High-Z). See Figure 5 for the output stage.

	DB15															DB0
ĺ	Х	Х	PD1	PD0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0

FIGURE 3. Data Input Register.

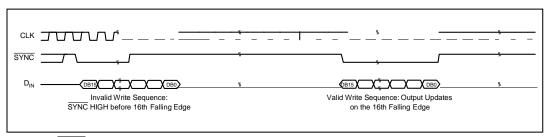


FIGURE 4. SYNC Interrupt Facility.

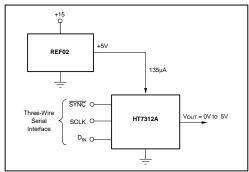


FIGURE 9. REF02 as Power Supply to HT7312A.

is loaded, the REF02 also needs to supply the current to the load. The total current required (with a $5k\Omega$ load on the DAC output) is:

$$135\mu A + (5V/5k\Omega) = 1.14mA$$

The load regulation of the REF02 is typically 0.005%/mA, which results in an error of $285\mu V$ for the 1.14mA current drawn from it. This corresponds to a 0.2LSB error.

BIPOLAR OPERATION USING THE HT7312A

The HT7312A has been designed for single-supply operation but a bipolar output range is also possible using the circuit in Figure 10. The circuit shown will give an output voltage range of ±5V. Rail-to-rail operation at the amplifier output is achievable using an OPA340 as the output amplifier.

The output voltage for any input code can be calculated as

$$\begin{array}{c} \text{follows:} \\ \text{V} = \begin{bmatrix} & \left(\begin{array}{c} \underline{D} \\ \end{array} \right) \\ \text{O} & \left[V & \left(\begin{array}{c} \underline{A} \\ \end{array} \right) \right] & \bullet \begin{bmatrix} \underline{R}_1 + \underline{R}_2 \\ \underline{R}_1 \end{bmatrix} \end{bmatrix} - \underbrace{V}_{DD} & \bullet \begin{bmatrix} \underline{R}_2 \\ \underline{R}_1 \end{bmatrix} \end{bmatrix}$$

where D represents the input code in decimal (0 -4095).

With $V_{DD} = 5V$, $R_1 = R_2 = 10k\Omega$:

$$V_0 = \left(\frac{10 \cdot D}{4096}\right) - 5V$$

This is an output voltage range of $\pm 5V$ with 000_{H} corresponding to a -5V output and FFF_H corresponding to a +5V output.

LAYOUT

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies. As the HT7312A offers single-supply operation, it will often be used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult it will be to achieve good performance from the converter.

Due to the single ground pin of the HT7312A, all return currents, including digital and analog return currents, must flow through the GND pin. Ideally, GND would be connected directly to an analog ground plane. This plane would be separate from the ground connection for the digital components until they were connected at the power entry point of the system.

The power applied to V_{DD} should be well regulated and low noise. Switching power supplies and DC/DC converters will often have high-frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high-frequency spikes as their internal logic switches states. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. This is particularly true for the HT7312A, as the power supply is also the reference voltage for the DAC.

As with the GND connection, V_{DD} should be connected to a +5V power supply plane or trace that is separate from the connection for digital logic until they are connected at the power entry point. In addition, the 1µF to 10µF and 0.1µF

bypass capacitors are strongly recommended. In some situations, additional bypassing may be required, such as a $100\mu F$ electrolytic capacitor or even a "Pi" filter made up of inductors and capacitors—all designed to essentially low-pass filter the +5V supply, removing the high-frequency noise.

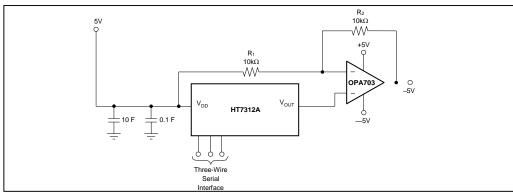
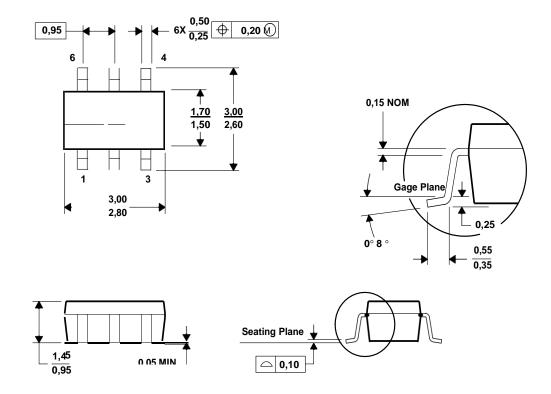


FIGURE 10. Bipolar Operation with the HT7312A.



SOT23-6



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing issubject to change without notice.
- C. Body dimensions donotincludemoldflashorprotrusion.
- D. Leads 1, 2, 3 may be wider than leads 4, 5, 6 for package orientation.

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BU2508FV-E2 BH2226F-E2 DAC8554IPWR DAC7641YB/250 TLV5638CDR DAC900TPWRQ1 MAX5318GUG+ MAX5705BAUB+
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